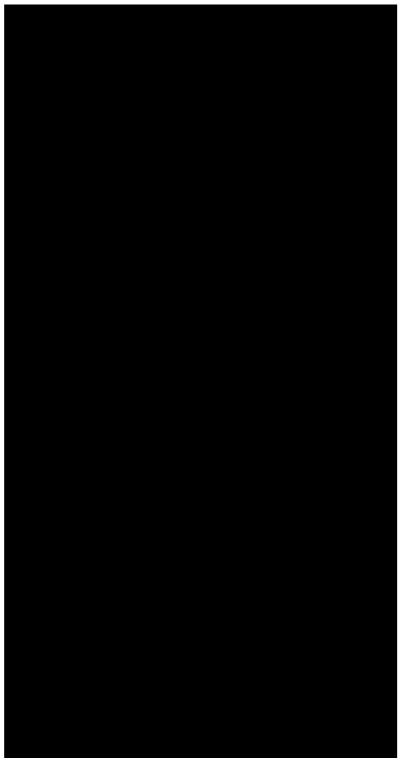
JST02UR-1000SW 2A TRIAC

Rev.A.2.1

DESCRIPTION:

The JST02UR-1000SW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST02UR-1000SW snubberless triac is especially recommended for use on inductive loads. It can be driven directly through the MCU I/O port. Package TO-92UR is RoHS compliant.



MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	2	A
V_{DRM} /V_{RRM}	1000	V
I_{GT} / /	10/10/10	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage (T_j=25)	V_{DRM}	1000	V
Repetitive peak reverse voltage (T_j=25)	V_{RRM}	1000	V
RMS on-state current	$I_{T(RMS)}$	2	A
Non repetitive surge peak on-state current (full cycle , t_p=20ms , T_j=25)	I_{TSM}	25	A
Non repetitive surge peak on-state current (full cycle , t_p=16.6ms , T_j=25)		27.5	
I^2t value for fusing (t_p=10ms , T_j=25)	I^2t	3.7	A^2s
Critical rate of rise of on-state current (I_G=2 × I_{GT} , f=100Hz , T_j=125)	dI/dt	100	A/μs
Peak gate current (t_p=20μs , T_j=125)	I_{GM}	2	A
Average gate power dissipation (T_j=125)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W

Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	4	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D =12V R_L =33Ω	- -	MAX.	10	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	V_D =V_{DRM} T_j =125 R_L =3.3kΩ	- -	MIN.	0.2	V
I_L	I_G =1.2I_{GT}	-	MAX.	20	mA
				30	
I_H	I_T =100mA		MAX.	15	mA
dV/dt	V_D=670V Gate Open T_j =125		MIN.	300	V/μs
(dI/dt)c	(dV/dt)c=10V/μs T_j=125		MIN.	1.5	A/ms
t_{on}	I_G=20mA I_A=200mA I_R=20mA T_j=25		TYP.	2.5	μs
t_{off}				25	

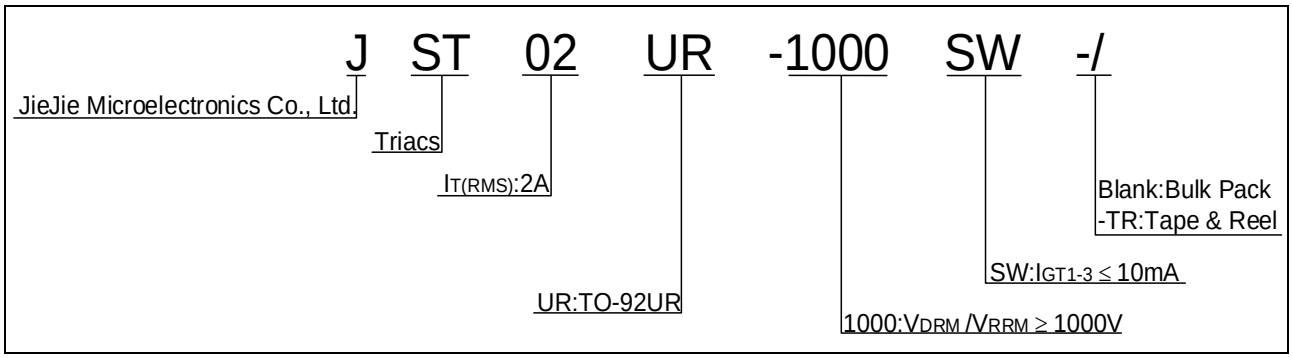
STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM} =3A t_p=380μs	T_j=25	1.5	V
V_{TO}	Threshold voltage	T_j=125	0.93	V
R_D	Dynamic resistance	T_j=125	146	mΩ
I_{DRM}	V_D =V_{DRM} V_R =V_{RRM}	T_j=25	8	μA
I_{RRM}		T_j=125	0.2	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	65	/W
$R_{th(j-a)}$	junction to ambient (AC)	160	/W

ORDERING INFORMATION



MARKING

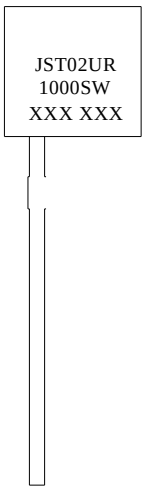


FIG.1: Maximum power dissipation versus RMS on-state current

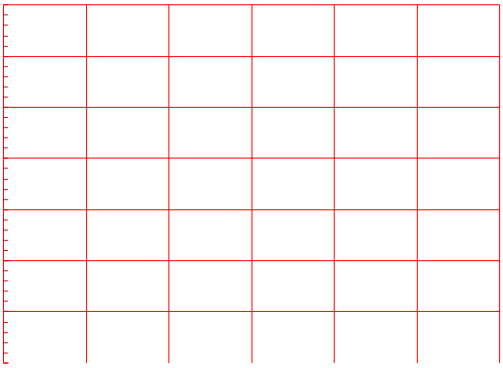


FIG.2: RMS on-state current versus case temperature

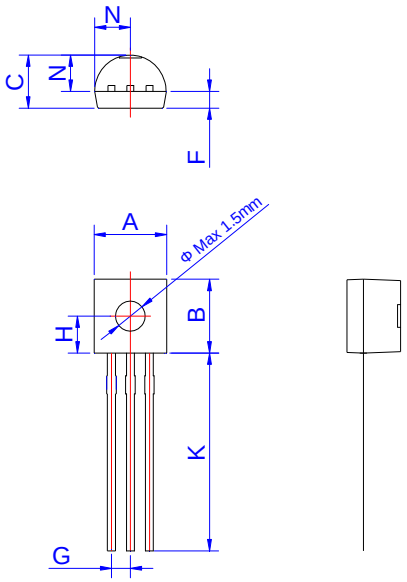
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
JST02UR-1000SW	1000	10	TO-92UR	1,000	Bulk Pack
JST02UR-1000SW-TR				2,000	Tape & Reel

Document Revision History

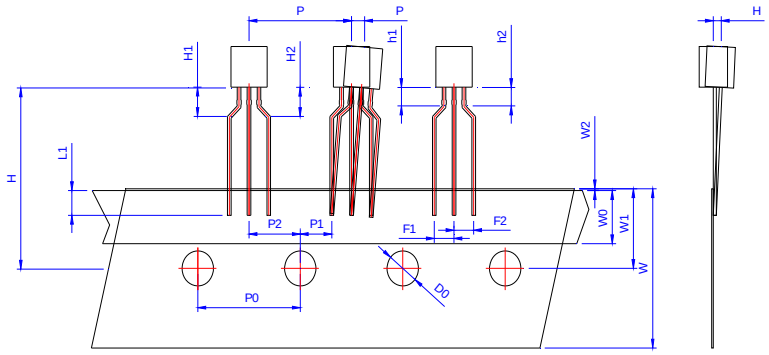
Date	Revision	Changes
Apr.10, 2023	A.1.0	Last updated
Apr.3, 2025	A.2.0	Renew PACKAGE MECHANICAL DATA
Sept.28, 2025	A.2.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



DELIVERY MODE

PACKAGE	OUTLINE	BAG (PCS)	INNER BOX (PCS)	CARTON BOX (PCS)
TO-92UR	Bulk Pack	1,000	10,000	50,000



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
P	12.40	12.70	13.00	0.488	0.500	0.512
P0	12.40	12.70	13.00	0.488	0.500	0.512
P1	3.55	3.85	4.15	0.140	0.152	0.163
P2	5.95	6.35	6.75	0.233	0.250	0.265
P	-1.00	0	1.00	-0.039	0	0.039
F1 F2	2.30	2.50	2.70	0.090	0.098	0.106
F1-F2	-0.10	0	0.10	-0.004	0	0.004
W	17.50	18.00	19.00	0.689	0.709	0.748
W0	5.50	6.00	6.50	0.217	0.236	0.256
W1	8.50	9.00	9.50	0.335	0.354	0.374
W2			1.00			0.039
D0	3.80	4.00	4.20	0.150	0.157	0.165
H	-1.00	0	1.00	-0.039	0	0.039
L1	2.50			0.098		
H	18.00	19.00	20.00	0.709	0.748	0.787
H1 H2			3.00			0.119
H1-H2	-0.50		0.50	-0.020		0.020
h1 h2			1.00			0.040
h1-h2	-0.20		0.20	-0.008		0.008

PACKAGE	OUTLINE	REEL (PCS)	INNER BOX (PCS)	CARTON BOX (PCS)
TO-92UR	Tape & Reel	/	2,000	20,000

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